Quad. 2-input Exclusive-OR Gates

HITACHI

ADE-205-257 (Z) 1st Edition March 1999

Description

The HD74LV86A performs the Boolean functions $Y = A \oplus B$ or $Y = \overline{AB} + A\overline{B}$ in positive logic. A common application is as a true/complement element. If one of the inputs is low, the other input will be reproduced in true form at the output. If one of the inputs is high, the other input will be reproduced inverted form at the output. Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0 \text{ V}$ to 5.5 V operation
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- All outputs V_0 (Max.) = 5.5 V (@V_{CC} = 0 V)
- Typical V_{OL} ground bounce < 0.8 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.3 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Output current $\pm 6 \text{ mA}$ (@V_{cc} = 3.0 V to 3.6 V), $\pm 12 \text{ mA}$ (@V_{cc} = 4.5 V to 5.5 V)

Function Table

Inputs

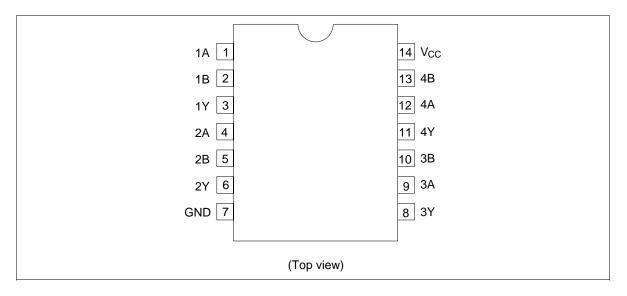
•		
Α	В	Output Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

Note: H: High level

L: Low level



Pin Arrangement



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Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{cc}	-0.5 to 7.0	V	
Input voltage range*1	V	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	–0.5 to V _{cc} + 0.5	V	Output: H or L
		-0.5 to 7.0		V _{cc} : OFF
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	Ι _{οκ}	±50	mA	$V_{\rm o}$ < 0 or $V_{\rm o}$ > $V_{\rm cc}$
Continuous output current	I _o	±25	mA	$V_{o} = 0$ to V_{cc}
Continuous current through V_{cc} or GND	$I_{\rm CC}$ or $I_{\rm GND}$	±50	mA	
Maximum power dissipation at Ta = 25° C (in still air)* ³	P _T	785	mW	SOP
		500		TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.

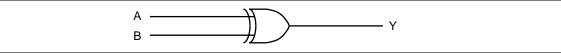
3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{cc}	2.0	5.5	V	
Input voltage range	V	0	5.5	V	
Output voltage range	Vo	0	V _{cc}	V	
Output current	I _{OH}	_	-50	μA	$V_{cc} = 2.0 V$
		_	-2	mA	V_{cc} = 2.3 to 2.7 V
		_	-6		V_{cc} = 3.0 to 3.6 V
		_	-12		V_{cc} = 4.5 to 5.5 V
	I _{ol}	_	50	μA	$V_{cc} = 2.0 V$
		_	2	mA	V_{cc} = 2.3 to 2.7 V
		_	6		V_{cc} = 3.0 to 3.6 V
		_	12		V_{cc} = 4.5 to 5.5 V
Input transition rise or fall rate	$\Delta t / \Delta v$	0	200	ns/V	V_{cc} = 2.3 to 2.7 V
		0	100		V_{cc} = 3.0 to 3.6 V
		0	20		V_{cc} = 4.5 to 5.5 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

• $Ta = -40 \text{ to } 85^{\circ}C$

Item	Symbol	V _{cc} (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} imes 0.7$	_	_		
		3.0 to 3.6	$V_{CC} imes 0.7$	_	_		
		4.5 to 5.5	$V_{CC} imes 0.7$	_	_	_	
	V _{IL}	2.0	_	_	0.5	_	
		2.3 to 2.7	_	_	$V_{CC} imes 0.3$	_	
		3.0 to 3.6	_	_	$V_{CC} imes 0.3$	_	
		4.5 to 5.5	_	_	$V_{CC} imes 0.3$	_	
Output voltage	V _{OH}	Min to Max	V _{cc} - 0.1	_	—	V	I _{OL} = -50 μA
		2.3	2.0	_	_		$I_{OL} = -2 \text{ mA}$
		3.0	2.48	_	_		$I_{OL} = -6 \text{ mA}$
		4.5	3.8	_	_	_	$I_{OL} = -12 \text{ mA}$
	V _{OL}	Min to Max	_	—	0.1	_	I _{OL} = 50 μA
		2.3	_	_	0.4	_	$I_{OL} = 2 \text{ mA}$
		3.0	_	_	0.44	_	I _{OL} = 6 mA
		4.5	_	_	0.55	_	I _{OL} = 12 mA
nput current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	I _{cc}	5.5	_	_	20	μA	$V_{IN} = V_{CC}$ or GND, $I_0 = 0$
Dutput leak current	I _{OFF}	0	_	_	5	μA	V ₀ = 5.5 V
nput capacitance	C _{IN}	3.3	_	TBD	_	pF	$V_1 = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

• $V_{CC} = 2.5 \pm 0.2 V$

		Ta = 25°C		Ta = −40 to 85°C						
ltem	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propa- gation delay time	t _{PLH} t _{PHL}	_	TBD	TBD	1.0	TBD	ns	C _L = 15 pF	A or B	Y
		—	TBD	TBD	1.0	TBD	-	C _L = 50 pF		

• $V_{CC} = 3.3 \pm 0.3 V$

	-		Ta = 25°C			40 to 85°C	_			
ltem	Symbol	Min	Тур	Max	Min	Мах	Unit	Test Conditions	FROM (Input)	TO (Output)
Propa- gation delay time	t _{PLH} t _{PHL}		7.0	11.0	1.0	13.0	ns	C _L = 15 pF	A or B	Y
		_	9.5	14.5	1.0	16.5	-	C _L = 50 pF		

• $V_{CC} = 5.0 \pm 0.5 \text{ V}$

		Ta = 25°C		Ta = −40 to 85°C		_				
ltem	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propa- gation delay time	t _{PLH} t _{PHL}	—	4.8	6.8	1.0	8.0	ns	C _L = 15 pF	A or B	Y
		_	6.3	8.8	1.0	10.0	-	C _L = 50 pF		

Operating Characteristics

• $C_L = 50 \text{ pF}$

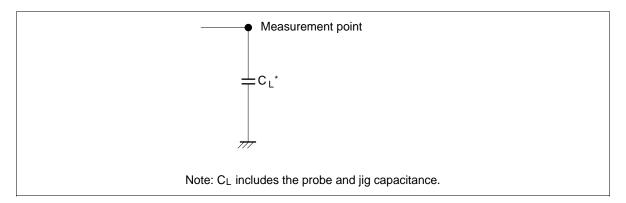
			Ta = 25°	°C			
ltem	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	C_{PD}	3.3	—	TBD	_	pF	f = 10 MHz
		5.0	_	TBD	—		

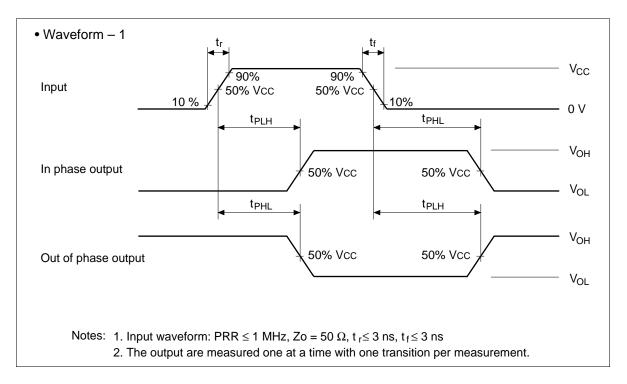
Noise Characteristics

• $C_L = 50 \text{ pF}$

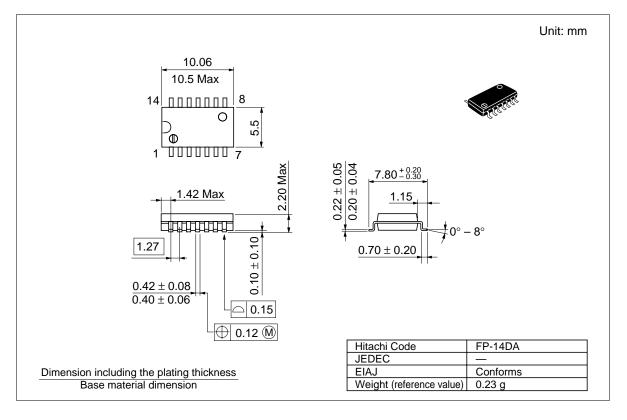
			Ta = 25°	°C			
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test Conditions
Quiet output, maximum dynamic V _{OL}	V _{OL (P)}	3.3	_	TBD	0.8	V	
Quiet output, minimum dynamic V _{oL}	V _{OL (V)}	3.3	—	TBD	-0.8		
Quiet output, minimum dynamic V _{он}	$V_{\text{OH}(V)}$	3.3	_	TBD	_		
High-level dynamic input voltage	V _{IH (D)}	3.3	2.31	_	_	V	_
Low-level dynamic inout voltage	$V_{\text{IL}(D)}$	3.3	_	_	0.99		

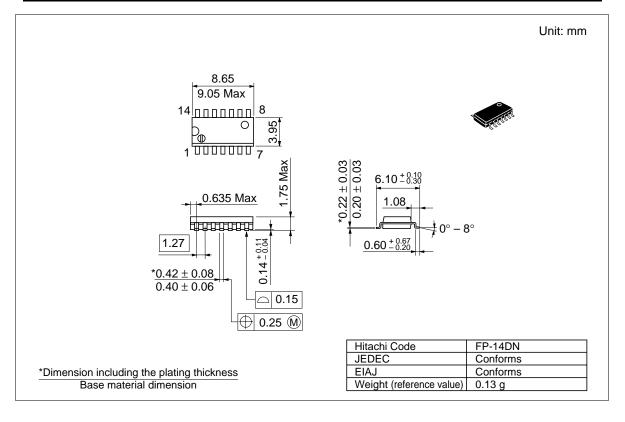
Test Circuit

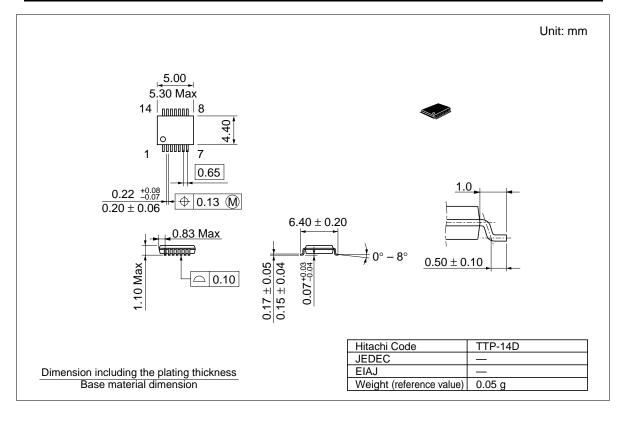




Package Dimensions







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